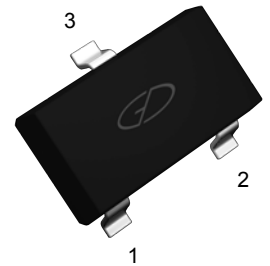


## Features

- High Current Low Voltage
- Complementary PNP MMBT2907A

## Applications

- General Purpose Amplifier
- Switching



**Package: SOT-23**

1. BASE
2. EMITTER
3. COLLECTOR

## Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

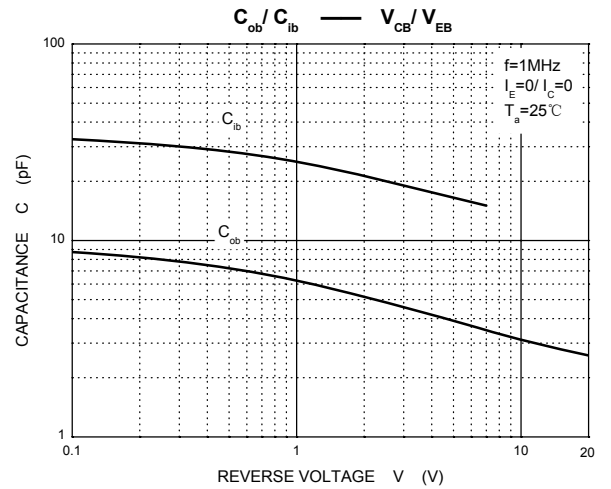
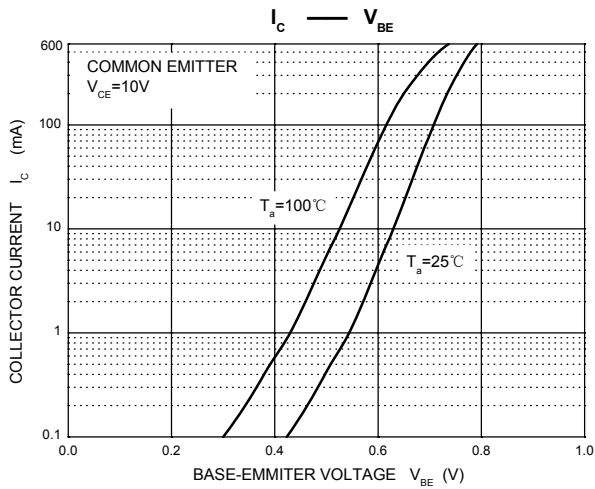
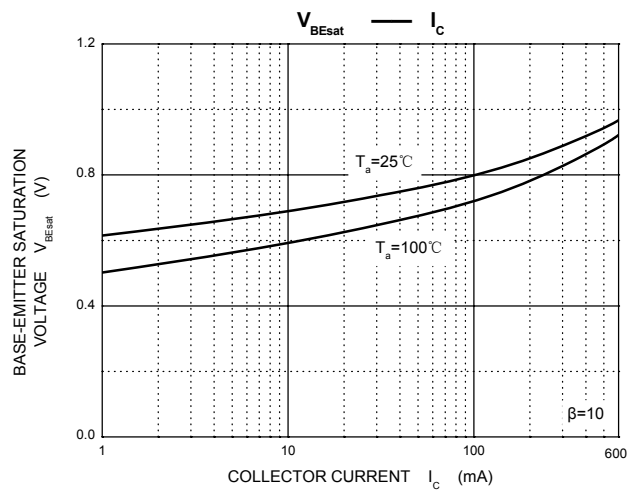
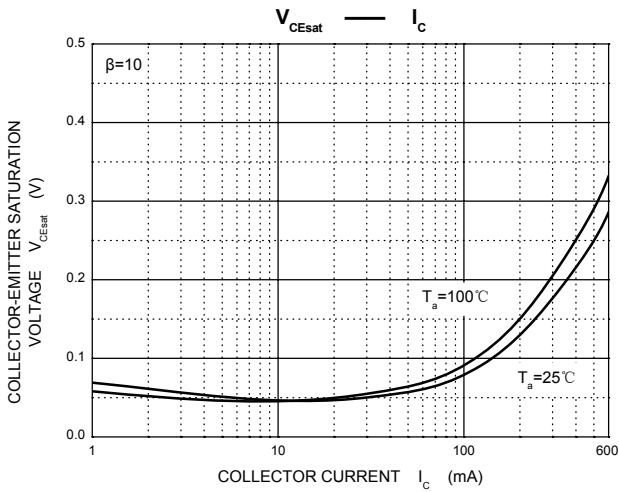
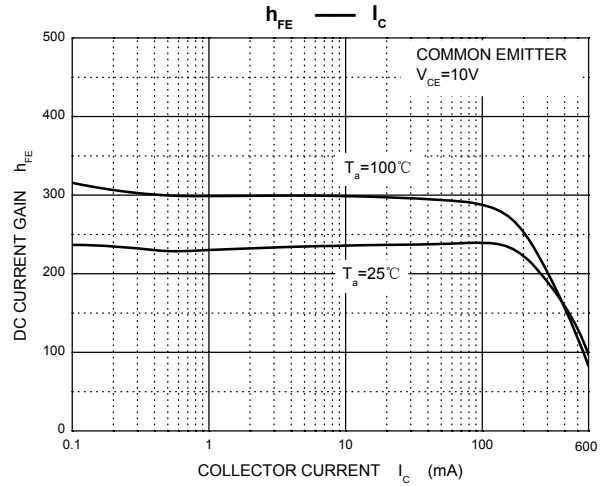
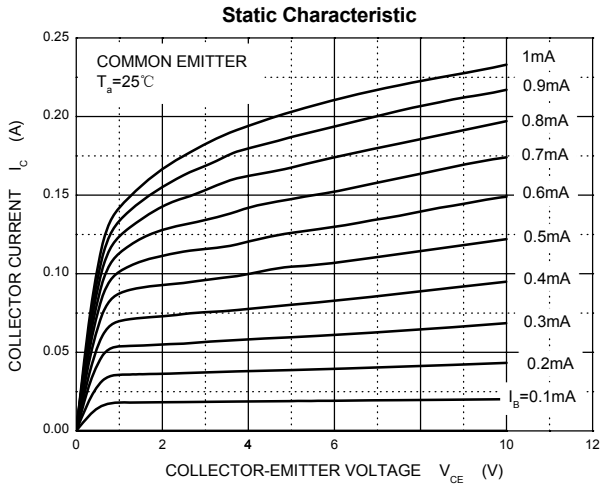
Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	75	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current-Continuous	$I_C$	600	mA
Collector Power Dissipation	$P_C$	300	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^{\circ}\text{C}/\text{W}$
Operating Temperature	$T_J$	-55 to +150	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-55 to +150	$^{\circ}\text{C}$

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

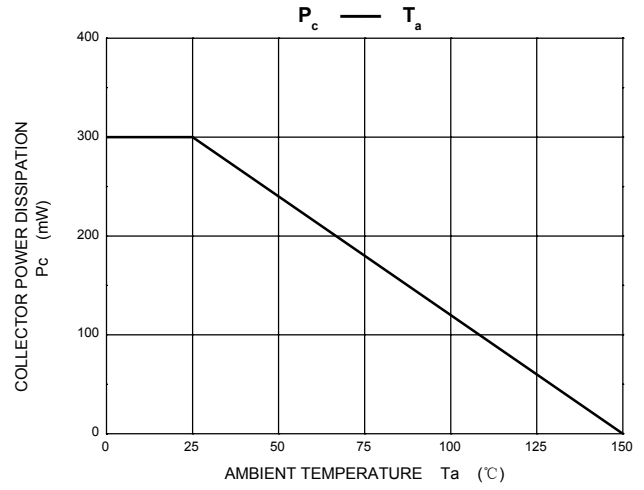
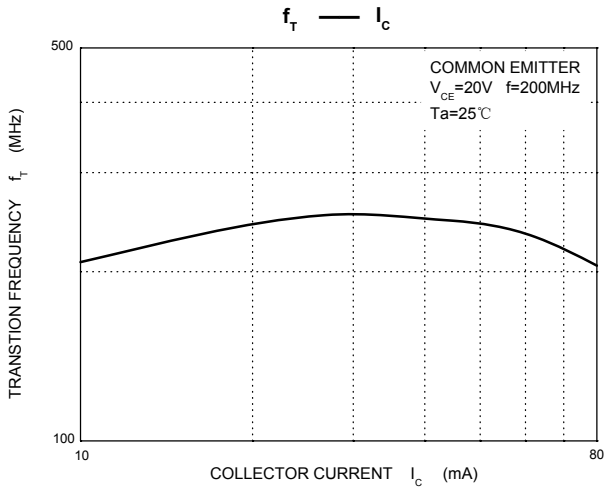
Parameters	Symbol	Test Conditions	Min	Max	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	75	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}^*$	$I_C=10\text{mA}, I_B=0$	40	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6	-	V
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=60\text{V}, I_E=0$	-	0.01	$\mu\text{A}$
Collector Cut-off Current	$I_{CEX}$	$V_{CE}=30\text{V}, V_{BE(off)}=3\text{V}$	-	0.01	$\mu\text{A}$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=3\text{V}, I_C=0$	-	0.1	$\mu\text{A}$
DC Current Gain	$h_{FE(1)}^*$	$V_{CE}=10\text{V}, I_C=150\text{mA}$	100	300	
	$h_{FE(2)}$	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	40	-	
	$h_{FE(3)}^*$	$V_{CE}=10\text{V}, I_C=500\text{mA}$	42	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}^*$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=150\text{mA}, I_B=15\text{mA}$	-	1 0.3	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}^*$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=150\text{mA}, I_B=15\text{mA}$	-	2.0 1.2	V
Transition Frequency	$f_T$	$V_{CE}=20\text{V}, I_C=20\text{mA},$ $f=100\text{MHz}$	300	-	MHz
Delay Time	$t_d$	$V_{CC}=30\text{V}, V_{BE(off)}=-0.5\text{V}$ $I_C=150\text{mA}, I_{B1}=15\text{mA}$	-	10	nS
Rise Time	$t_r$		-	25	nS
Storage Time	$t_s$	$V_{CC}=30\text{V}, I_C=150\text{mA}$ $I_{B1}=-I_{B2}=15\text{mA}$	-	225	nS
Fall Time	$t_f$		-	60	nS

\*pulse test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

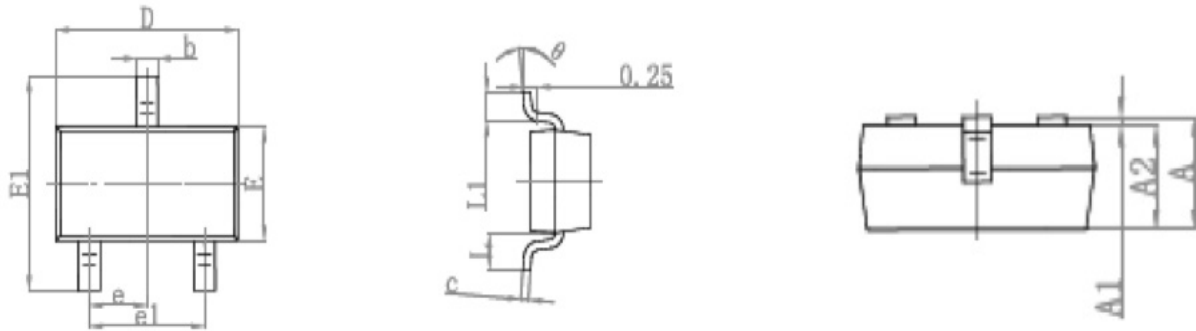
**Electrical Characteristic Curves**



**Electrical Characteristic Curves**

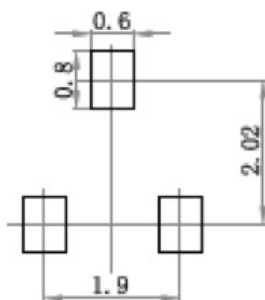


**Package Outline Dimensions SOT-23**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°

**Suggested Pad Layout**



- Note:
1. Controlling dimension: in millimeters.
  2. General tolerance:  $\pm 0.05$ mm.
  3. The pad layout is for reference purposes only.